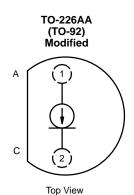


Vishay Siliconix

Current Regulator Diodes

J500	J503	J506	J509	
J501	J504	J507	J510	
J502	J505	J508	J511	

PRODUCT SUMMARY								
Part Number	Typ I _F (mA)	P _{OV} (V)		Part Number	Typ I _F (mA)	P _{OV} (V)		
J500	0.24	50		J506	1.40	50		
J501	0.33	50		J507	1.80	50		
J502	0.43	50		J508	2.40	50		
J503	0.56	50		J509	3.00	50		
J504	0.75	50		J510	3.60	50		
J505	1.00	50		J511	4.70	50		



FEATURES

- Two-Lead PlasticPackage
- Guaranteed ±20% Tolerance
- Operation from 1 V (J500–J503) to 50 V
- Excellent Temperature Stability

BENEFITS

- Simple Series Circuitry, No Separate Voltage Source
- Tight Guaranteed Circuit Performance
- Excellent Performance in Low-Voltage/Battery Circuits and High-Voltage Spike Protection
- High Circuit Stability vs. Temperature

APPLICATIONS

- Constant-Current Supply
- Current-Limiting
- Timing Circuits

DESCRIPTION

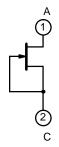
The J500 series is a family of $\pm\,20\%$ range current regulators designed for demanding applications in test equipment and instrumentation. These devices utilize the JFET techniques to produce a single two-leaded device which is extremely simple to operate.

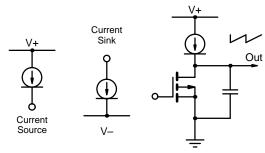
With nominal current ranges from 0.24 mA to 4.7 mA, the J500 series will meet a wide array of design requirements.

The low-cost TO-226A package ensures a cost-effective design solution.

SCHEMATIC DIAGRAM

APPLICATIONS





Linear Ramp Generator

Applications information may be obtained via FaxBack, request document #70596.

J500 Series

Vishay Siliconix



ABSOLUTE MAXIMUM RATINGS

Peak Operating Voltage	. 50 V	Power Dissipation ^a	350 mV
Reverse Current 5	50 mA	Notes:	
Storage Temperature	150°C	a. Derate 2.8 mW/°C above 25°C	

SPECIFICATIONS ²									
			Limits						
Parameter	Symbol	Test Conditions	Min	Typ NO TAG	Max	Unit			
Peak Operating Voltage	Pov	$I_F = 1.1 I_{F(max)}$ NO TAG	50	95		V			
Reverse Voltage	V _R	I _R = 1 mA	0.0	0.8		1			
Capacitance	C _F	V _F = 25 V, f = 1 MHz		2.2		pF			

	Regulator Current ^d (I _F)		Imped	Dynamic Knee Impedance (Z _d) (Z _k)		Limiting Voltage ^f (V _L)		Temperature Coefficient (θ ₁)	
		V _F = 25 V		V _F = 25 V		V _F = 6 V	$I_{F} = 0.8 \; I_{F(min)}$		$V_F = 25 \text{ V}$ $0^{\circ}\text{C} \le T_A \le 100^{\circ}\text{C}$
		mA		MΩ		MΩ	V		%/°C
Part Number	Min	Nom	Max	Min	Typb	Typ ^b	Max	Typb	Typ ^b
J500	0.192	0.24	0.288	4.00	15	2.50	1.2	0.4	0.95%
J501	0.264	0.33	0.396	2.20	10	1.60	1.3	0.5	0.81%
J502	0.344	0.43	0.516	1.50	7	1.10	1.5	0.6	0.70%
J503	0.448	0.56	0.672	1.20	5	0.80	1.7	0.7	0.58%
J504	0.600	0.75	0.900	0.80	3.5	0.55	1.9	0.8	0.46%
J505	0.800	1.00	1.200	0.50	2	0.40	2.1	0.9	0.33%
J506	1.120	1.40	1.680	0.33	1.5	0.25	2.5	1.1	0.19%
J507	1.440	1.80	2.160	0.20	1	0.19	2.8	1.3	0.08%
J508	1.900	2.40	2.900	0.20	0.7	0.13	3.1	1.5	-0.05%
J509	2.400	3.00	3.600	0.15	0.5	0.09	3.5	1.7	-0.14%
J510	2.900	3.60	4.300	0.15	0.4	0.07	3.9	1.9	-0.22%
J511	3.800	4.70	5.600	0.12	0.3	0.05	4.2	2.1	-0.34%

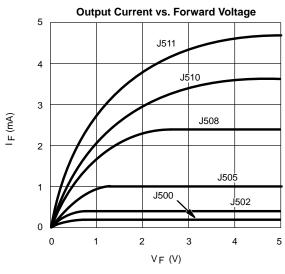
Notes:

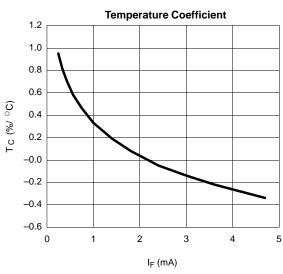
NCL

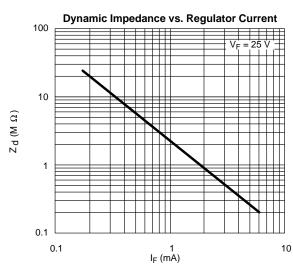
- Notes:
 a. $T_A = 25^{\circ}\text{C}$ unless otherwise noted.
 b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
 c. $\text{Max } V_F \text{ where } I_F = 1.1 \ I_{F(max)} \text{ is guaranteed.}$ d. Pulse test—steady state currents may vary.
 e. Pulse test—steady state impedances may vary.
 f. $\text{Min } V_F \text{ required to insure } I_F = 0.8 \ I_{F(min)}.$

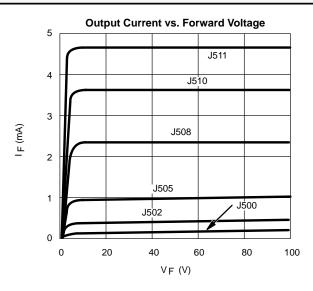


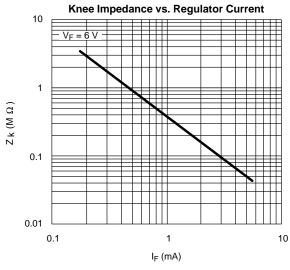
TYPICAL CHARACTERISTICS

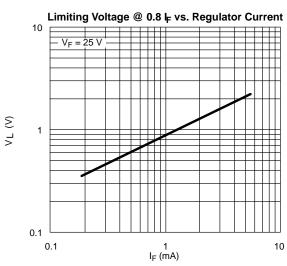








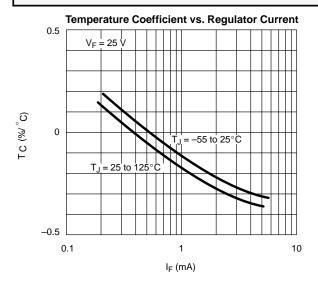


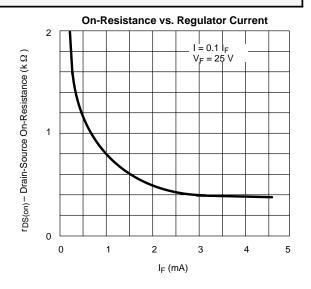


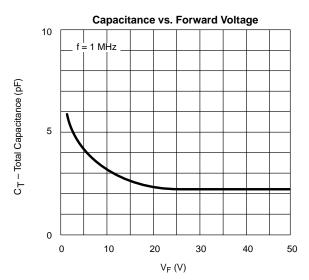
Vishay Siliconix



TYPICAL CHARACTERISTICS







CURRENT REGULATOR DIODE V-1 CHARACTERISTIC

